

BF3510TV

FULL 50-60Hz RECTIFICATION BRIDGE

MAIN PRODUCT CHARACTERISTICS

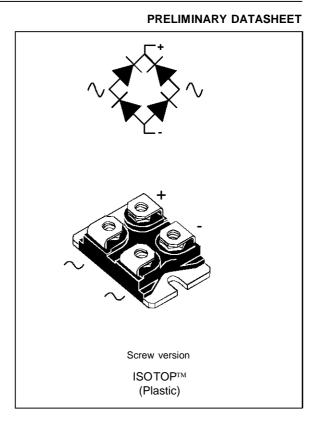
lF(AV)	35A		
V _{RRM}	1000V		
V _F (max)	1.3V		

FEATURES AND BENEFITS

- COMPACT ISOTOP DESIGN COMPATIBLE WITH FAST DIODES, TRANSISTORS AND PASSIVE COMPONENTS.
- EXCELLENT THERMAL TRANSFER JUNC-TION TI HEATSINK
- UL PENDING

DESCRIPTION

The Bridges series from SGS-THOMSON has been designed to allow a better standardization of packages on boards principally designed with ISOTOP packages. The insulated package of the bridge will be able to sit on heatsink with other components. Single phase and 3-phase high power SMPS, UPS, MOTOR DRIVES and WELDING equipment will primarily find advantage in these industry package products.



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (per diode unless specified)

Symbol	Parameter	Value	Unit	
VRRM	Repetitive peak reverse voltage	1000	V	
V _{RSM}	Non repetitive peak reverse voltage	1000	V	
IF(AV) total	Average forward current	Tc=80°C Sinus		А
IFSM	Surge non repetitive forward current 50Hz JEDEC method	300	А	
l ² .t	Fusing	660	A ² .s	
Tstg	Storage temperature range	- 65 to + 150	°C	
Tj	Max. operating junction temperature	150	°C	
Pmax total	Total power dissipation	50	W	

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THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rth (j-c) total	Junction to case	0.5	°C/W

ELECTRICAL CHARACTERISTICS (Per diode)

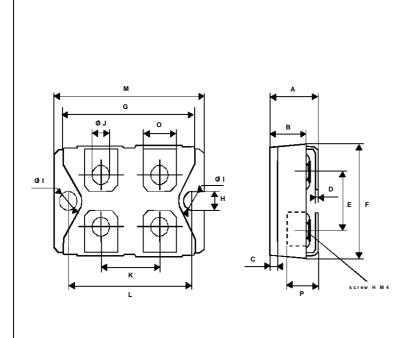
STATIC CHARACTERISTICS

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I _R *	Reverse leakage current	V _R = 0.8 V _{RRM}	T _j = 25°C			10	μΑ
		$\delta < 2\%$ tp = 5ms	T 10500			0.2	mA
VF **	Forward voltage drop	I _F = 35 A δ < 2% tp = 380μs	T _j = 25°C			1.4	V
			T _j = 125°C			1.3	V

Pulse test : * tp = 5 ms, duty cycle < 2 % ** tp = 380 μ s, duty cycle < 2 %

For one diode: Pcond = 1.02 x $I_{F(AV)}$ + 0.008 x $I_{F(RMS)}$ and $I_{F(RMS)}$ and $I_{F(AV)}$ + $I_{F(AV)}$ +

PACKAGE DATA (millimeter) ISOTOP (Plastic)



REF.	DIMENSIONS				
	Millimeters		Inc	hes	
	Min.	Max.	Min.	Max.	
Α	11.80	12.20	0.465	0.480	
В	8.90	9.10	0.350	0.358	
С	1.95	2.05	0.077	0.081	
D	0.75	0.85	0.029	0.034	
Е	12.60	12.80	0.496	0.504	
F	25.10	25.50	0.988	1.004	
G	31.50	31.70	1.240	1.248	
Н	4.00		0.157		
I	4.10	4.30	0.161	0.169	
J	4.10	4.30	0.161	0.169	
K	14.90	15.10	0.586	0.595	
L	30.10	30.30	1.185	1.193	
М	37.80	38.20	1.488	1.504	
0	7.80	8.20	0.307	0.323	
Р	5.50		0.216		

Cooling method : C Electrical isolation : 2500V_(RMS)

Marking : Type number Capacitance : < 45 pF Weight : 28 g. (without screws) Inductance : < 5 nH

- Recommended torque value: 1.3 N.m (MAX 1.5 N.m) for the 6 x M4 screws. (2 x M4 screws recommended for mounting the package on the heatsink and the 4 screws given with the screw version).
- The screws supplied with the package are adapted for mounting on a board (or other types of terminals) with a thickness of 0.6 mm min and 2.2 mm max.

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